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Vishay Semiconductors

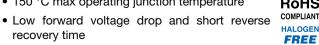
Fast Soft Recovery Rectifier Diode, 20 A



PRIMARY CHARACTERISTICS							
I _{F(AV)}	20 A						
V _R	200 V, 400 V, 600 V						
V _F at I _F	1.3 V						
I _{FSM}	300 A						
t _{rr}	60 ns						
T _J max.	150 °C						
Snap factor	0.6						
Package	TO-220AC 2L						
Circuit configuration	Single						

FEATURES

- · Glass passivated pellet chip junction
- 150 °C max operating junction temperature



- Designed and qualified according JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

These devices are intended for use in output rectification and freewheeling in inverters, choppers and converters as well as in input rectification where severe restrictions on conducted EMI should be met.

DESCRIPTION

The VS-20ETF0... fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	CHARACTERISTICS	VALUES	UNITS					
V _{RRM}	Range	200 to 600	V					
I _{F(AV)}	Sinusoidal waveform	20						
I _{FSM}		300	A					
t _{rr}	1 A, 100 A/μs	60	ns					
V _F	10 A, T _J = 25 °C	1.2	V					
T _J	Range	-40 to +150	°C					

VOLTAGE RATINGS									
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA						
VS-20ETF02-M3	200	300							
VS-20ETF04-M3	400	500	5						
VS-20ETF06-M3	600	700							

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum average forward current	I _{F(AV)}	T _C = 97 °C, 180° conduction half sine wave	20					
Maximum peak one cycle	I _{FSM}	10 ms sine pulse, rated V _{RRM} applied	250	Α				
non-repetitive surge current		10 ms sine pulse, no voltage reapplied	300					
Maximum I ² t for fusing	I ² t	10 ms sine pulse, rated V _{RRM} applied	316	A ² s				
waximum i-t for fusing	1-1	10 ms sine pulse, no voltage reapplied 442		A-5				
Maximum I ² √t for fusing	l²√t	t = 0.1 to 10 ms, no voltage reapplied	4420	A ² √s				



ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST COI	NDITIONS	VALUES	UNITS			
Maximum forward voltage drop	V_{FM}	20 A, T _J = 25 °C		1.3	V			
Forward slope resistance	r _t	T _{.1} = 150 °C		12.5	mΩ			
Threshold voltage	V _{F(TO)}	1J = 150 C		0.9	V			
Maximum roverse leakage current	1	T _J = 25 °C	V - Poted V	0.1	mA			
Maximum reverse leakage current	IRM	T _J = 150 °C	V _R = Rated V _{RRM}	5.0	IIIA			

RECOVERY CHARACTERISTICS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	· •				
Reverse recovery time	t _{rr}	I _F at 20 A _{pk}	160	ns	I _{FM} †				
Reverse recovery current	I _{rr}	100 A/µs	10	Α	$t_a \mid t_b$				
Reverse recovery charge	Q _{rr}	25 °C	1.25	μC	dir/ Q				
Snap factor	S	Typical	0.6		dt I _{RM(REC)}				

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction and storage temperature range	T _J , T _{Stg}		-40 to +150	°C				
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	0.9					
Maximum thermal resistance, junction to ambient	R _{thJA}		62	°C/W				
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, and greased	0.5					
Approximate weight			2	g				
Approximate weight			0.07	oz.				
Mounting torque minimum			6 (5)	kgf ⋅ cm				
Mounting torque maximum			12 (10)	(lbf \cdot in)				
Marking device		Case style TO-220AC 2L	20ET 20ET 20ET	F04				



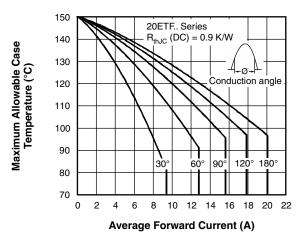


Fig. 1 - Current Rating Characteristics

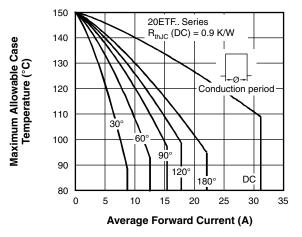


Fig. 2 - Current Rating Characteristics

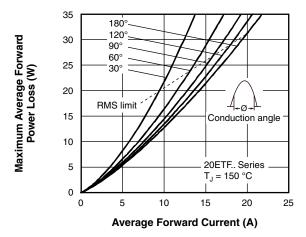


Fig. 3 - Forward Power Loss Characteristics

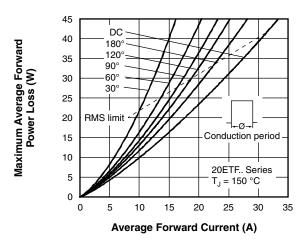


Fig. 4 - Forward Power Loss Characteristics

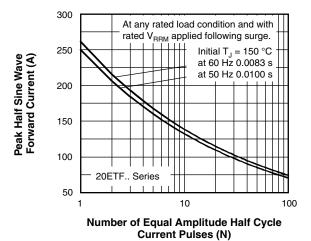


Fig. 5 - Maximum Non-Repetitive Surge Current

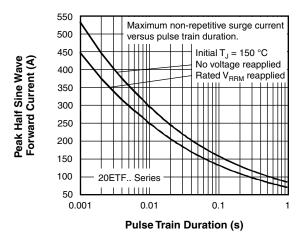


Fig. 6 - Maximum Non-Repetitive Surge Current

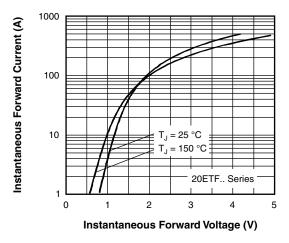


Fig. 7 - Forward Voltage Drop Characteristics

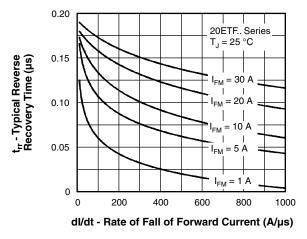


Fig. 8 - Recovery Time Characteristics, $T_J = 25 \, ^{\circ}\text{C}$

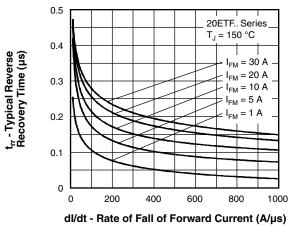


Fig. 9 - Recovery Time Characteristics, $T_J = 150~^{\circ}\text{C}$

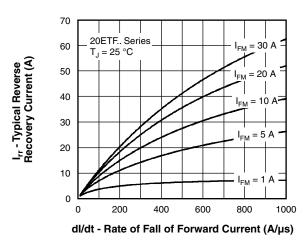


Fig. 10 - Recovery Charge Characteristics, T_J = 25 °C

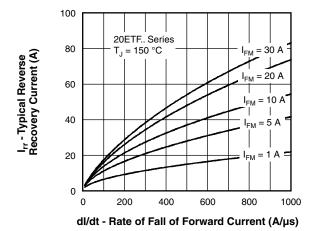
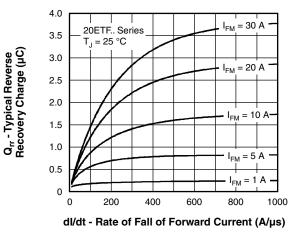


Fig. 11 - Recovery Charge Characteristics, $T_J = 150 \, ^{\circ}\text{C}$



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Q_{rr}-Typical Reverse Recovery Charge (µC)

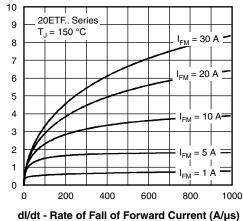


Fig. 12 - Recovery Current Characteristics, $T_J = 25~^{\circ}\text{C}$

Fig. 13 - Recovery Current Characteristics, T_J = 150 °C

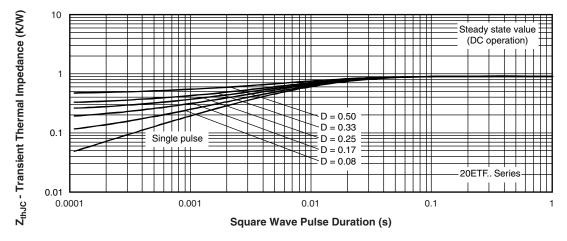
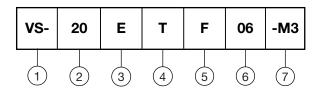


Fig. 14 - Thermal Impedance Z_{thJC} Characteristics



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (20 = 20 A)

3 - Circuit configuration:

E = single

4 - Package:

T = 2L TO-220AC

5 - Type of silicon:

F = fast soft recovery rectifier

02 = 200 V04 = 400 V

6 - Voltage code x 100 = V_{RRM}

04 = 400 V06 = 600 V

7 - Environmental digit

-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)								
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION						
VS-20ETF02-M3	50	Antistatic plastic tube						
VS-20ETF04-M3	50	Antistatic plastic tube						
VS-20ETF06-M3	50	Antistatic plastic tube						

LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?96156					
Part marking information	www.vishay.com/doc?95391					



TO-220AC 2L

DIMENSIONS in millimeters and inches





Conforms to JEDEC® outline TO-220AC

SYMBOL	MILLIM	MILLIMETERS		INCHES		NOTES S'	SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183			D2	11.68	13.30	0.460	0.524	6, 7
A1	1.14	1.40	0.045	0.055			Е	10.11	10.51	0.398	0.414	3, 6
A2	2.50	2.92	0.098	0.115			E1	6.86	8.89	0.270	0.350	6
b	0.69	1.01	0.027	0.040			е	2.41	2.67	0.095	0.105	
b1	0.38	0.97	0.015	0.038	4		e1	4.88	5.28	0.192	0.208	
b2	1.20	1.73	0.047	0.068			H1	6.09	6.48	0.240	0.255	6
b3	1.14	1.73	0.045	0.068	4		L	13.52	14.02	0.532	0.552	
С	0.36	0.61	0.014	0.024			L1	3.32	3.82	0.131	0.150	2
c1	0.36	0.56	0.014	0.022	4		ØΡ	3.54	3.91	0.139	0.154	
D	14.85	15.35	0.585	0.604	3		Q	2.60	3.00	0.102	0.118	
D1	8.38	9.02	0.330	0.355				•	•			

Notes

- ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3, and c1 apply to base metal only
- Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- (7) Outline conforms to JEDEC® TO-220, except D2



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